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APPLICATION NO.	f FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/028,276	12/28/2001	Shunpei Yamazaki	740756-2414	2826	
22204	7590 12/10/2003		EXAMINER		
NIXON PEABODY, LLP			PIZIALI, JEFFREY J		
401 9TH STREET, NW SUITE 900			ART UNIT	PAPER NUMBER	
	N, DC 20004-2128		2673	Δ	
			DATE MAIL ED. 12/10/2003	DATE MAIL ED: 12/10/2003	

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)	6
Office Action Summers	10/028,276	YAMAZAKI ET AL.	
Office Action Summary	Examiner	Art Unit	
	Jeff Piziali	2673	
The MAILING DATE of this communication ap Period for Reply	pears on the cover sheet with	n the correspondence address	•
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1. after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a replif NO period for reply is specified above, the maximum statutory period. - Failure to reply within the set or extended period for reply will, by statut. - Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b). Status	136(a). In no event, however, may a repoly within the statutory minimum of thirty will apply and will expire SIX (6) MONT i.e. cause the application to become ABA	oly be timely filed (30) days will be considered timely. HS from the mailing date of this communica NDONED (35 U.S.C. § 133).	lion.
1) Responsive to communication(s) filed on 28 L	December 2001.		
2a) ☐ This action is FINAL . 2b) ☑ This	action is non-final.		
3) Since this application is in condition for allowated closed in accordance with the practice under	ance except for formal matte Ex parte Quayle, 1935 C.D.	rs, prosecution as to the merits 11, 453 O.G. 213.	is
Disposition of Claims			
4)⊠ Claim(s) <u>1-20</u> is/are pending in the application	١.		
4a) Of the above claim(s) is/are withdra	awn from consideration.		
5) Claim(s) is/are allowed.			
6)⊠ Claim(s) <u>1-20</u> is/are rejected.			
7) ☐ Claim(s) is/are objected to.			
8) Claim(s) are subject to restriction and/	or election requirement.		
Application Papers		`	
9)☐ The specification is objected to by the Examin			
10)⊠ The drawing(s) filed on <u>28 December 2001</u> is/			
Applicant may not request that any objection to the		The state of the s	
Replacement drawing sheet(s) including the correct			` '
11)☐ The oath or declaration is objected to by the E	xaminer. Note the attached	Office Action or form PTO-152.	
Priority under 35 U.S.C. §§ 119 and 120	,		
12) ☐ Acknowledgment is made of a claim for foreig a) ☐ All b) ☐ Some * c) ☐ None of: 1. ☐ Certified copies of the priority documen 2. ☐ Certified copies of the priority documen 3. ☐ Copies of the certified copies of the priority documen application from the International Burea * See the attached detailed Office action for a list	ts have been received. ts have been received in Apority documents have been received in (PCT Rule 17.2(a)).	plication No. <u>09/144,538</u> . eceived in this National Stage	
 13) Acknowledgment is made of a claim for domest since a specific reference was included in the fit 37 CFR 1.78. a) The translation of the foreign language pr 	tic priority under 35 U.S.C. § st sentence of the specificat	119(e) (to a provisional application or in an Application Data Sl	ition) heet.
14) Acknowledgment is made of a claim for domest reference was included in the first sentence of the	ic priority under 35 U.S.C. §	§ 120 and/or 121 since a speci	fic 78.
Attachment(s)			
Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of Info	mmary (PTO-413) Paper No(s) ormal Patent Application (PTO-152)	

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DETAILED ACTION

Drawings

1. Figure 24 should be designated by a legend such as --Prior Art-- because only that which is old is illustrated. See MPEP § 608.02(g). A proposed drawing correction or corrected drawings are required in reply to the Office action to avoid abandonment of the application. The objection to the drawings will not be held in abeyance.

Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 3. Claims 1, 2, 7, 9, 10, 13, and 14 are rejected under 35 U.S.C. 102(b) as being anticipated by Riggio, Jr. (US 5,452,250).

Regarding claim 1, Riggio discloses an electronic device [Fig. 3; 34] comprising a nonvolatile memory [Figs. 5A & 5B; 60-1 to 60-n], wherein the nonvolatile memory comprises a memory element [Fig. 5A; 60-1], and wherein the memory element comprises a first thin film transistor [Fig. 5A; FGT1] comprising a floating gate and a second thin film transistor [Fig. 5A; FGT2] (see Column 4, Line 5 - Column 6, Line 14).

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Regarding claim 2, this claim is rejected by the reasoning applied in the above rejection of claim 1; furthermore Riggio discloses a source electrode [Fig. 1; 14] and a drain electrode [Fig. 1; 16] of the memory element comprise the same material [i.e. aluminum] as that of a gate electrode [Fig. 1; 12] of the first thin film transistor (see Column 2, Lines 32-65).

Regarding claim 7, this claim is rejected by the reasoning applied in the above rejection of claim 2.

Regarding claim 9, Riggio discloses each of the first thin film transistor and the second thin film transistor comprises a semiconductor layer comprising a source region [Fig. 2; 14], a drain region [Fig. 2; 16], a low concentration impurity region [Fig. 2; 26 & 28], and a channel region [Fig. 2; 24] (see Column 2, Line 32 - Column 3, Line 23).

Regarding claim 10, this claim is rejected by the reasoning applied in the above rejection of claim 9.

Regarding claim 13, Riggio discloses the first thin film transistor is a n-channel FAMOS type thin film transistor and the second thin film transistor is an n-channel switching thin film transistor (see Figs. 1 & 2; Column 1, Lines 37-50). Riggio does not expressly disclose a p-channel FAMOS type thin film transistor. However, at the time of invention, p-channel FAMOS type TFTs were a well known and commonly understood design alternative to n-channel FAMOS type TFTs. Therefore, it would have been obvious to one skilled in the art at the time

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of invention to substitute Riggio's n-channel FAMOS type TFT with a p-channel FAMOS type TFT, as a matter of transistor design choice.

Regarding claim 14, this claim is rejected by the reasoning applied in the above rejection of claim 13.

Claim Rejections - 35 USC § 103

- 4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 5. Claims 17 and 18 are rejected under 35 U.S.C. 103(a) as being unpatentable over Riggio, Jr. (US 5,452,250) in view of the prior art disclosed in the instant application.

Regarding claim 17, Riggio does not expressly disclose the electronic device is one of the group consisting of a projection display system, a video camera, a still camera, a head mount display, a car navigation system, a personal computer, and a portable information terminal. However, the instant application's admitted prior art discloses the electronic device being one of the group consisting of a projection display system, a video camera, a still camera, a head mount display, a car navigation system, a personal computer, and a portable information terminal (see Page 2, Line 30 - Page 3, Line 11). Riggio and the instant application's admitted prior art are analogous art, because they are from the shared field of semiconductor memory devices.

Therefore, it would have been obvious to use Riggio's memory device with one of the above

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listed electronic devices, so as to protect some commercially popular electronic devices from data loss in the event of power disruptions.

Regarding claim 18, this claim is rejected by the reasoning applied in the above rejection of claim 17.

6. Claims 3-6, 8, 11, 12, 15, and 16 are rejected under 35 U.S.C. 103(a) as being unpatentable over Riggio, Jr. (US 5,452,250) in view of Tanaka et al. (US 5,798,744) and Gutierrez (US 4,305,083).

Regarding claim 3, this claim is rejected by the reasoning applied in the above rejection of claim 1; however, Riggio does not explicitly disclose a semiconductor display device comprising a pixel region comprising a plurality of pixel thin film transistors, wherein gate electrodes of the plurality of pixel thin film transistors, the floating gate, and a gate electrode of the second thin film transistor comprise the same material.

Tanaka does disclose a semiconductor display device [i.e. liquid crystal display] comprising a pixel region [Fig. 1; 40] comprising a plurality of pixel thin film transistors [Fig. 2; 101], and wherein gate electrodes [Fig. 2; 113] of the plurality of pixel thin film transistors are made of aluminum (see Column 5, Line 37 - Column 6, Line 10). Moreover, Gutierrez discloses an aluminum floating gate [Fig. 2; 21] (see Column 1, Lines 9-28). Riggio, Tanaka, and Gutierrez are analogous art, because they are from the shared field of transistor based circuitry.

Therefore, it would have been obvious to one skilled in the art at the time of invention to use Gutierrez' aluminum floating gate as Riggio's floating gate, so as to utilize an inexpensive,

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electrically conductive electrode material; and further to use this combined nonvolatile memory with Tanaka's display device, so as to store display information in such a manner that it can be recovered/restored following a power loss.

Regarding claim 4, this claim is rejected by the reasoning applied in the above rejection of claims 1-3.

Regarding claim 5, this claim is rejected by the reasoning applied in the above rejection of claim 3.

Regarding claim 6, this claim is rejected by the reasoning applied in the above rejection of claim 3.

Regarding claim 8, this claim is rejected by the reasoning applied in the above rejection of claim 2.

Regarding claim 11, this claim is rejected by the reasoning applied in the above rejection of claim 9; furthermore Tanaka discloses each of the pixel thin film transistors comprises a semiconductor layer comprising a source region [Fig. 3; 120], a drain region [Fig. 3; 130], a low concentration impurity region [Fig. 3; 135], and a channel region [Fig. 3; 110] (see Column 5, Line 53 - Column 6, Line 10).

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Regarding claim 12, this claim is rejected by the reasoning applied in the above rejection of claims 9 and 11.

Regarding claim 15, this claim is rejected by the reasoning applied in the above rejection of claim 13.

Regarding claim 16, this claim is rejected by the reasoning applied in the above rejection of claim 13.

7. Claims 19 and 20 are rejected under 35 U.S.C. 103(a) as being unpatentable over Riggio, Jr. (US 5,452,250) in view of Tanaka et al. (US 5,798,744) and Gutierrez (US 4,305,083), and further in view of the prior art disclosed in the instant application.

Regarding claim 19, this claim is rejected by the reasoning applied in the above rejection of claim 17.

Regarding claim 20, this claim is rejected by the reasoning applied in the above rejection of claim 17.

Claim Rejections - 35 USC § 112

8. The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

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- 9. Claims 9-12 rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.
- 10. The term "low concentration impurity region" in claims 9-12 is a relative term which renders the claim indefinite. The term "low concentration impurity region" is not defined by the claim, the specification does not provide a standard for ascertaining the requisite degree, and one of ordinary skill in the art would not be reasonably apprised of the scope of the invention. It is unclear given present claim language, what precisely constitutes a "low concentration impurity region" versus, for instance, a "high concentration impurity region."

Conclusion

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. Iwahashi (US 5,008,856), Kanbara (US 5,036,231), Yoshizawa et al. (US 5,040,147), Kodama (US 5,274,602), Glenn (US 5,274,602), Yamada et al. (US 5,278,428), Ochii (US 5,315,546), Koyama et al. (US 5,321,286), Ozawa (US 5,477,068), Akiyama et al. (US 5,493,139), Riggio (US 5,523,970), Iwahashi (US 5,610,858), and Young (US 5,621,683) are cited to further evidence the state of the art pertaining to electronic devices.

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Any inquiry concerning this communication or earlier communications from the examiner should be directed to Jeff Piziali whose telephone number is (703) 305-8382. The examiner can normally be reached on Monday - Friday (6:30AM - 3PM).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Bipin Shalwala can be reached on (703) 305-4938. The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9314.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 305-4700.

2 December 2003

BIPIN SHALWALA SUPERVISORY COLUENT ENAMINER TECHNOLOGY CENTER 2800